#### AM2300N

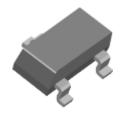
## **Analog Power**

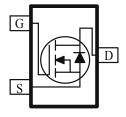
## N-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low  $r_{DS(on)}$  assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are DC-DC converters, power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

- Low r<sub>DS(on)</sub> Provides Higher Efficiency and Extends Battery Life
- Low gate charge 7nC
- High performance
- High current handling
- Miniature SOT-23 Surface Mount Package Saves Board Space

PRODUCT SUMMARY			
$V_{DS}(V)$	$r_{D}$	I <sub>D</sub> (A)	
20	0.035 @ V <sub>GS</sub> = 4.5V	4.3	
	$0.050 @ V_{GS} = 2.5V$	3.5	





ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25 °C UNLESS OTHERWISE NOTED)					
Parameter		Symbol	Maximum	Units	
Drain-Source Voltage			20	V	
Gate-Source Voltage			$\pm 8$	v	
Continuous Drain Current <sup>a</sup>	$T_A = 25^{\circ}C$	I.,	4.3	А	
Continuous Drain Current	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	1D	3.3		
Pulsed Drain Current <sup>b</sup>		I <sub>DM</sub>	10		
Continuous Source Current (Diode Conduction) <sup>a</sup>			0.46	А	
Power Dissipation <sup>a</sup>	$T_{A}=25^{\circ}C$ $T_{A}=70^{\circ}C$	P <sub>D</sub>	1.25	W	
Power Dissipation	$T_A = 70^{\circ}C$	тD	0.8	, v	
Operating Junction and Storage Temperature Range			-55 to 150	°C	

THERMAL RESISTANCE RATINGS				
Parameter		Symbol	Maximum	Units
Mariana Investion to Archient <sup>a</sup>	t <= 5 sec	D	100	°C/W
Maximum Junction-to-Ambient <sup>a</sup>	Steady-State	R <sub>THJA</sub>	166	

Notes

a. Surface Mounted on 1" x 1" FR4 Board.

b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS ( $T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)						
Parameter	Symbol	Test Conditions			TT4	
Farameter	Symbol	Test Conditions	Min	Тур	Max	Unit
Static						
Gate-Threshold Voltage	V <sub>GS(th)</sub>	$V_{DS} = V_{GS}, I_D = 250 \text{ uA}$	0.7			
Gate-Body Leakage	I <sub>GSS</sub>	$V_{DS} = 0 V, V_{GS} = 8 V$			100	nA
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	$V_{DS} = 16 V, V_{GS} = 0 V$			1	uA
	035	$V_{DS} = 20 V, V_{GS} = 0 V, T_J = 55^{\circ}C$			10	
On-State Drain Current <sup>A</sup>	I <sub>D(on)</sub>	$V_{DS} = 5 V, V_{GS} = 4.5 V$	10			А
Drain-Source On-Resistance <sup>A</sup>	r <sub>DS(on)</sub>	$V_{GS} = 4.5 \text{ V}, I_D = 4.3 \text{ A}$		30	35	mΩ
Dram-Source On-Resistance		$V_{GS} = 2.5 \text{ V}, I_D = 3.5 \text{ A}$		40	50	
Forward Tranconductance <sup>A</sup>	$g_{\rm fs}$	$V_{DS} = 5 V, I_D = 3.0 A$		11		S
Diode Forward Voltage	V <sub>SD</sub>	$I_{\rm S} = 0.46$ A, $V_{\rm GS} = 0$ V		0.65	1.20	V
Dynamic <sup>b</sup>			-			-
Total Gate Charge	Qg	$V_{DS} = 10 \text{ V}, V_{GS} = 4.5 \text{ V},$		7.0		nC
Gate-Source Charge	Q <sub>gs</sub>	$V_{\rm DS} = 10$ V, $V_{\rm GS} = 4.5$ V, $I_{\rm D} = 3.0$ A		1.20		
Gate-Drain Charge	Q <sub>gd</sub>	$I_{\rm D} = 5.0$ A		1.90		
Input Capacitance	C <sub>iss</sub>	$V_{DS} = 15 V, V_{GS} = 0 V,$		700		pF
Output Capacitance	C <sub>oss</sub>	$v_{\rm DS} = 13 v$ , $v_{\rm GS} = 0 v$ , f = 1MHz		175		
Reverse Transfer Capacitance	C <sub>rss</sub>	I = IIMHZ		85		
Turn-On Delay Time	t <sub>d(on)</sub>			9		ns
Rise Time	t <sub>r</sub>	$V_{DD} = 10 V$ , $I_D = 1 A$ ,		11		
Turn-Off Delay Time	t <sub>d(off)</sub>	$R_{\rm G} = 6 \ \Omega$ , $V_{\rm GEN} = 4.5 \ V$		18		
Fall-Time	t <sub>f</sub>			5		

Notes

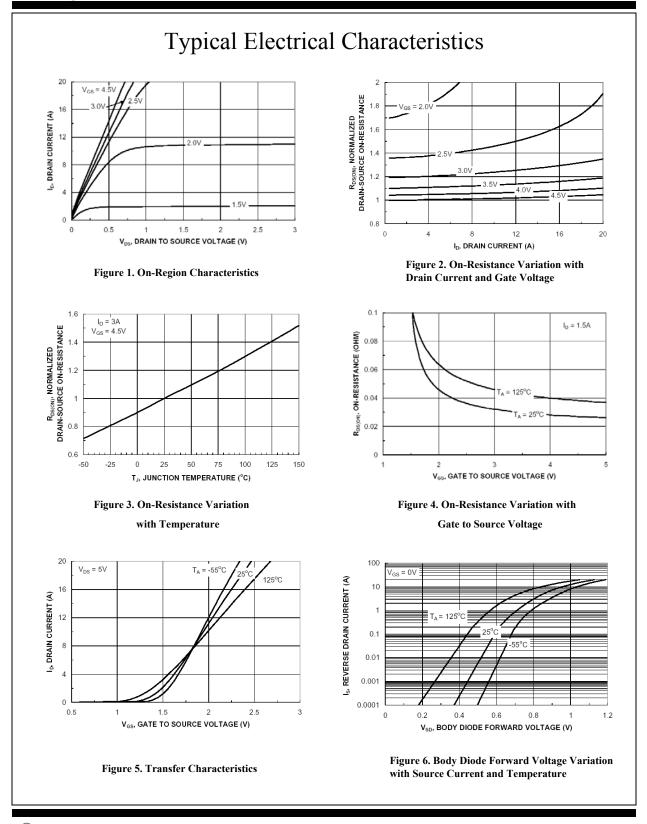
a. Pulse test:  $PW \le 300$ us duty cycle  $\le 2\%$ .

b. Guaranteed by design, not subject to production testing.

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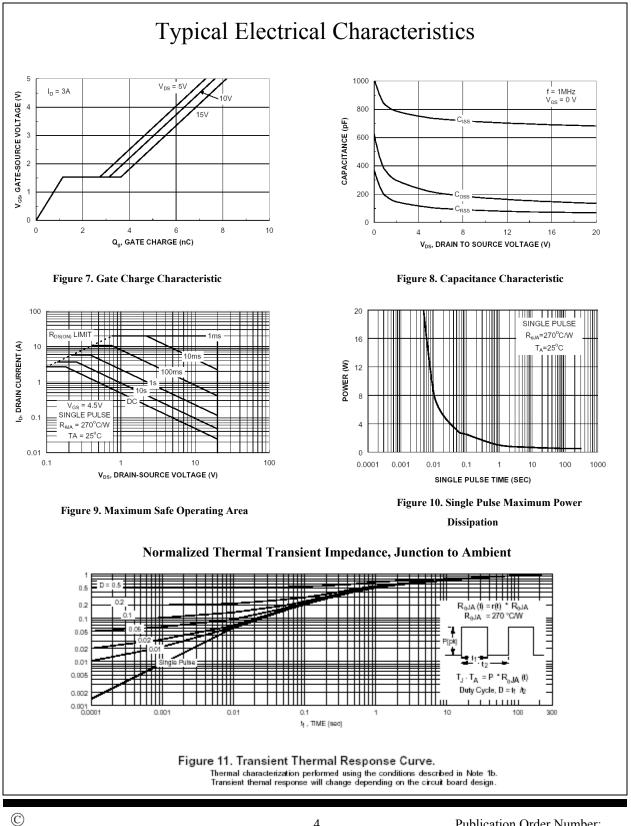
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# Package Information

